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RFMD(R) to Present Industry-Leading Products and Technologies at 2011 Mobile World Congress in Barcelona

GREENSBORO, N.C., Feb. 10, 2011 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced the Company will present a broad selection of industry-leading radio frequency (RF) components for the global mobile device market at the 2011 Mobile World Congress (MWC) in Barcelona, Spain from February 14 to February 17, 2011.

The RF components to be highlighted by RFMD® at MWC 2011 will span the Company's broad portfolio of power amplifier-based and switch-based products for GSM/GPRS/EDGE, WEDGE, WCDMA, LTE, WiFi, and WiMAX devices.

RFMD will feature its recently launched PowerSmart™ power platforms, which leverage the Company's proprietary RF Configurable Power Core™ and deliver multiband coverage of all cellular communications modulation schemes (2G/3G/4G, up to LTE 64QAM). The Company will also display a new product family of single-mode 3G power amplifiers that deliver breakthrough current consumption, as well as a new 3G power platform for the mass market smartphone segment and a selection of switch-based products optimized for the high-band count and complex harmonic requirements of 4G LTE smartphones and tablets.

RFMD will also showcase its 3G/4G wireless infrastructure product portfolio and its expanding family of high-performance RF components for microwave point-to-point radios.

RFMD offers the industry's most innovative portfolio of radio frequency components, including cellular power amplifier modules, cellular transmit modules, antenna switch modules, switch filter modules, switch duplexer modules, and front ends for Wi-Fi, WiMAX and GPS applications. RFMD also offers an expanding portfolio of wireless infrastructure products, including the world's most efficient broadband GaN power amplifier for 3G/4G base stations.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance semiconductor components. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled

personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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